

60 V, 1 A PNP/PNP low VCEsat transistor

6 November 2023

**Product data sheet** 

### 1. General description

PNP/PNP low V<sub>CEsat</sub> transistor pair in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4160DS

### 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- + High collector current capability  ${\rm I}_{\rm C}$  and  ${\rm I}_{\rm CM}$
- + High collector current gain ( $h_{FE}$ ) at high  $I_C$
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors
- AEC-Q101 qualified

### 3. Applications

- Dual low power switches (e.g. motors, fans)
- Automotive applications

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per transist	or						_
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-60	V
I <sub>C</sub>	collector current		[1]	-	-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	-2	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -1 A; $I_B$ = -100 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C		-	250	330	mΩ

[1] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

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### 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1		
3	C2	collector TR2		
4	E2	emitter TR2		
5	B2	base TR2	TSOP6 (SOT457)	 E1 B1 C2
6	C1	collector TR1		sym138

### 6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PBSS5160DS	TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	<u>SOT457</u>		

### 7. Marking

Table 4.	Marking	codes
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Type number	Marking code
PBSS5160DS	A5

### 8. Limiting values

#### Table 5. Limiting values

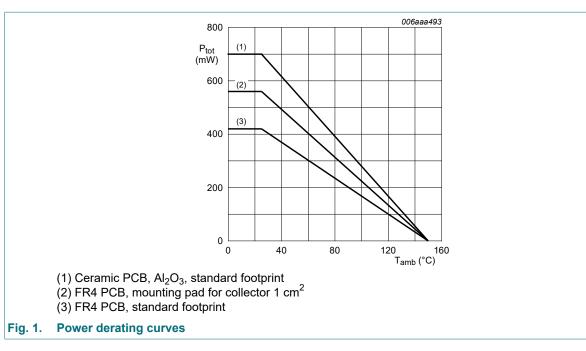
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	tor					
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-80	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current		[1]	-	-0.77	А
			[2]	-	-0.9	А
			[3]	-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	А
I <sub>B</sub>	base current			-	-300	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-1	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	290	mW
			[2]	-	370	mW
			[3]	-	450	mW
Per device						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	420	mW
			[2]	-	560	mW
			[3]	-	700	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.



### 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per transist	tor						
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	-	431 H	K/W
	junction to ambient		[2]	-	-	338	K/W
			[3]	-	-	278	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	105	K/W
Per device			L				
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	-	298	K/W
	junction to ambient	[2]	-	223	K/W		
			[3]	-	-	179	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

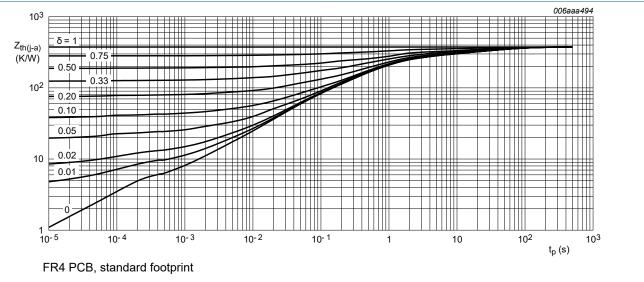
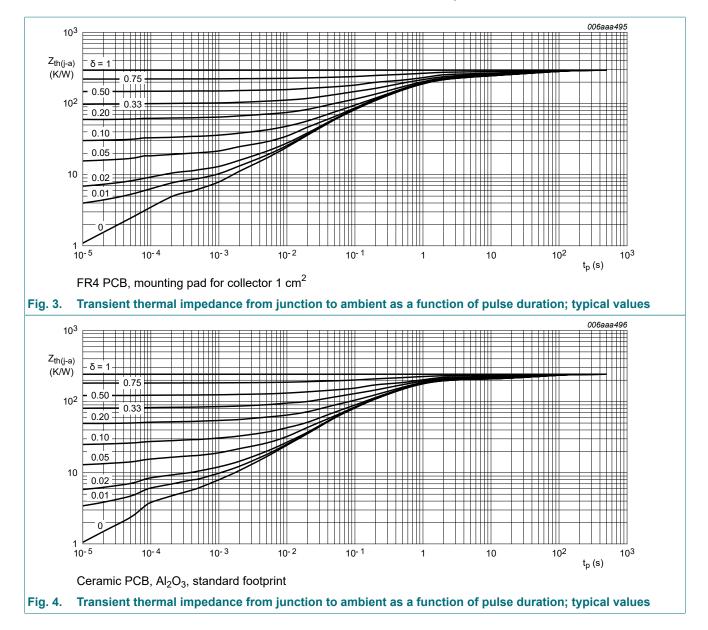


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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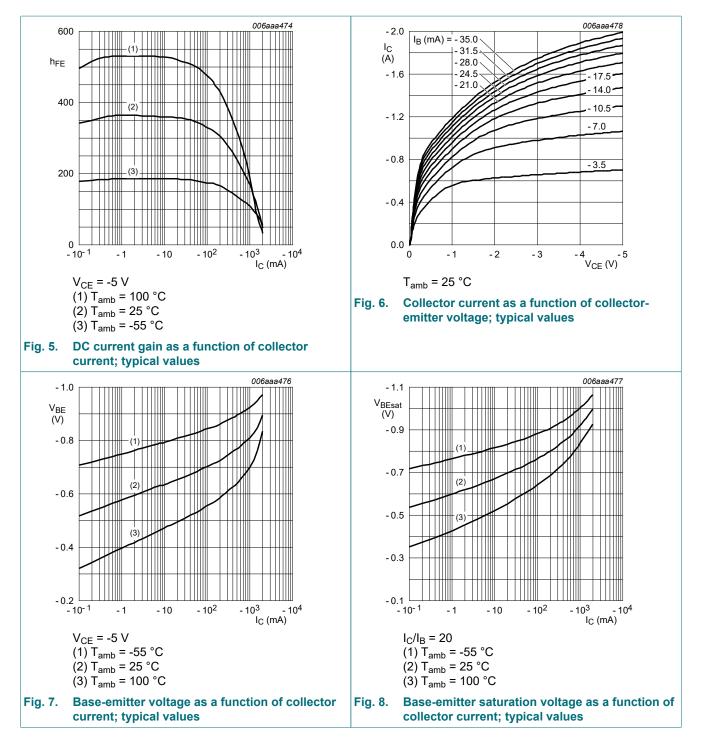
PBSS5160DS

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### **10. Characteristics**

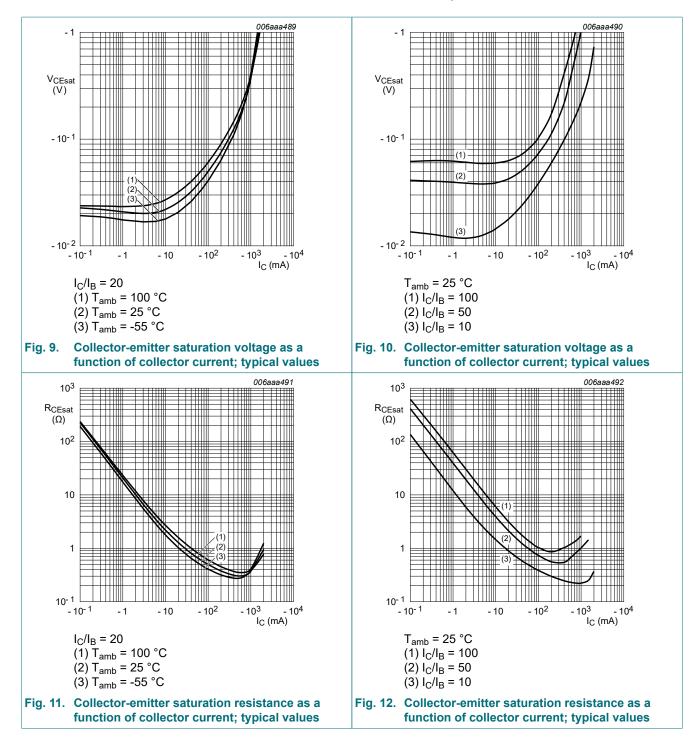
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor	11				
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -60 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -60 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = -60 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 mA; T <sub>amb</sub> = 25 °C	200	350	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -500 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	150	250	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	100	160	-	
V <sub>CEsat</sub>		I <sub>C</sub> = -100 mA; I <sub>B</sub> = -1 mA; T <sub>amb</sub> = 25 °C	-	-110	-165	mV
	saturation voltage	I <sub>C</sub> = -500 mA; I <sub>B</sub> = -50 mA; T <sub>amb</sub> = 25 °C	-	-120	-175	mV
		$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-250	-330	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance		-	250	330	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -1 A; $I_B$ = -50 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-0.95	-1.1	V
V <sub>BEon</sub>	base-emitter turn-on voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-0.82	-0.9	V
t <sub>d</sub>	delay time	I <sub>C</sub> = -0.5 A; I <sub>Bon</sub> = -25 mA; I <sub>Boff</sub> = 25 mA;	-	11	-	ns
t <sub>r</sub>	rise time	T <sub>amb</sub> = 25 °C	-	30	-	ns
t <sub>on</sub>	turn-on time		-	41	-	ns
t <sub>s</sub>	storage time		-	205	-	ns
t <sub>f</sub>	fall time		-	55	-	ns
t <sub>off</sub>	turn-off time		-	260	-	ns
f⊤	transition frequency	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	150	185	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	9	15	pF

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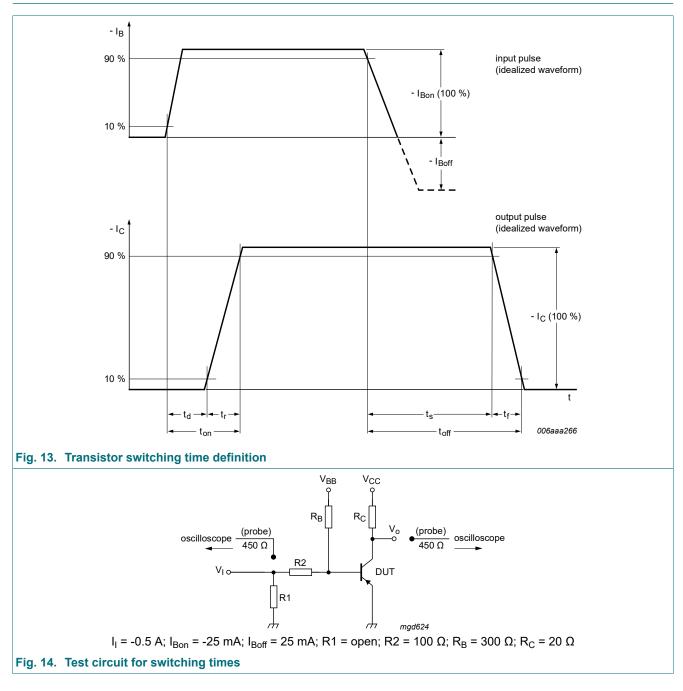


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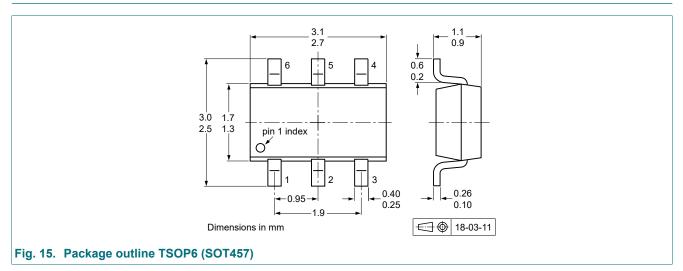
### **11. Test information**



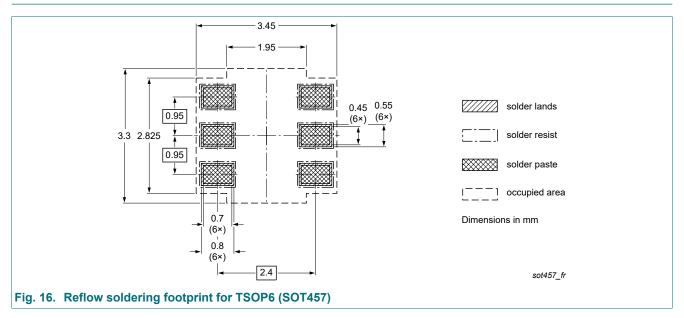
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

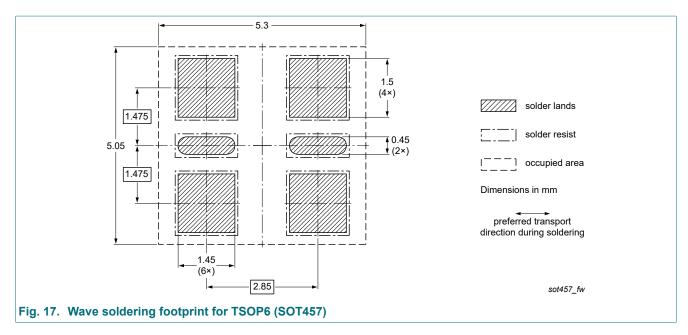
### 12. Package outline



### 13. Soldering



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### 14. Revision history

Table 8. Revision his	story					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS5160DS v.4	20231106	Product data sheet	-	PBSS5160DS_3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Section "Packing information" removed.</li> </ul>					
PBSS5160DS_3	20081009	Product data sheet	-	PBSS5160DS_2		
PBSS5160DS_2	20050628	Product data sheet	-	PBSS5160DS_1		
PBSS5160DS_1	20040716	Objective data sheet	-	-		

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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